NSN 5962-01-160-0194

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View Online at https://aerobasegroup.com/nsn/5962-01-160-0194

Body Length:	
0.430 inches	
Body Width:	
Between 0.245 inches and 0.285 inc	hes
Body Height:	
Between 0.045 inches and 0.090 inc	hes
Maximum Power Dissipation Ratin	ıg:
575.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+175.0 degrees celsius	
Features Provided:	
Hermetically sealed and programmal	ble and expandable and w/enable and wire-or outputs
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Flat pack	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
8 input	
Case Outline Source And Designa	itor:
F-8 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Char	racteristic:
5.5 volts power source	
Time Rating Per Chacteristic:	
140.00 nanoseconds propagation de	elay time, low to high level output and 140.00 nanoseconds propagation delay time, high to low level
output	
Rom	
Test Data Document:	
35351-166799 drawing (this is the ba	asic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard	d or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:	
24 flat leads	
Shelf Life:	
N/a	
Time Rating Per Chacteristic: 140.00 nanoseconds propagation de output Memory Device Type: Rom Test Data Document: 35351-166799 drawing (this is the bas excludes any specification, standard Terminal Type And Quantity: 24 flat leads Shelf Life:	

Demilitarization:

Yes - demil/mli

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